

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
-60V	4.2Ω@-10V	-0.13A
	4.5Ω@-4.5V	

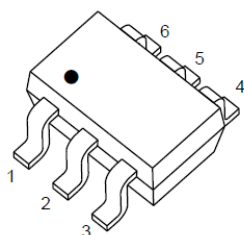
Feature

- Energy Efficient
- Low Threshold Voltage
- High-speed Switching
- Miniature Surface Mount Package Saves Board Space

Application

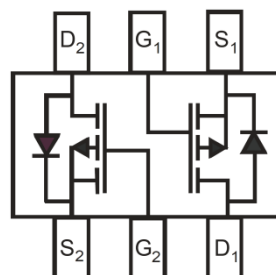
- DC-DC converters
- load switching
- power management in portable
- battery-powered products

Package

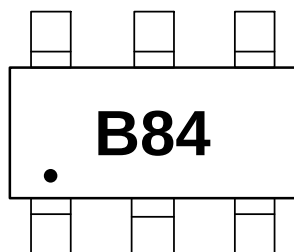


SOT-363

Circuit diagram



Marking



B84 =Device Code

Absolute maximum ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	-0.13	A
Plused Drain Current ⁽¹⁾ @tp<10μs	I_{DM}	-0.52	A
Power Dissipation	P_D	200	mW
Thermal Resistance from Junction to Ambient ⁽²⁾	$R_{\theta JA}$	625	°C/W
Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55~ +150	°C

Electrical characteristics (T_A=25 °C, unless otherwise noted)

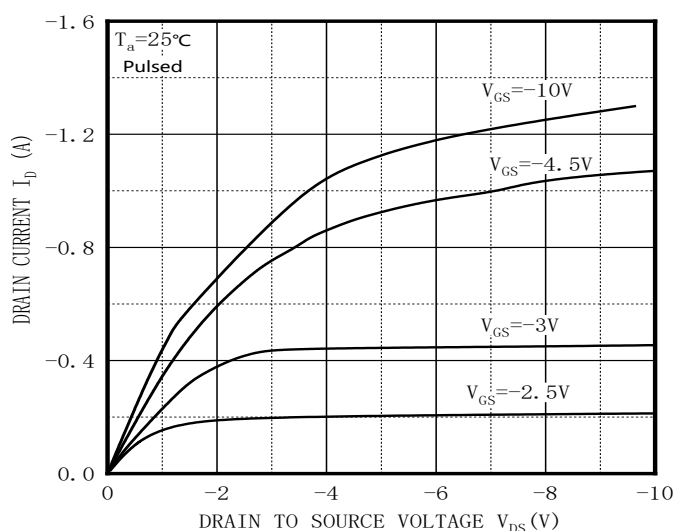
Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-60	-	-	V
Drain Leakage Current	I_{DSS}	$V_{DS} = -48V, V_{GS} = 0V$	-	-	-1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
Gate threshold voltage ³⁾	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-0.8	-1.5	-2.5	V
Drain-source on-resistance ³⁾	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -0.15A$	-	4.2	6	Ω
		$V_{GS} = -4.5V, I_D = -0.15A$	-	4.5	7	
Dynamic characteristics ⁴⁾						
Input Capacitance	C_{iss}	$V_{DS} = -5V, V_{GS} = 0V, f = 1MHz$	-	30	-	pF
Output Capacitance	C_{oss}		-	10	-	
Reverse Transfer Capacitance	C_{rss}		-	5	-	
Switching characteristics ⁴⁾						
Turn-on delay time	$t_{d(on)}$	$V_{DD} = -15V, R_L = 50\Omega, I_D = -2.5A$	-	2.5	-	ns
Turn-on rise time	t_r		-	1	-	
Turn-off delay time	$t_{d(off)}$		-	16	-	
Turn-off fall time	t_f		-	8	-	
Source-Drain Diode characteristics						
Diode Forward voltage	V_{SD}	$V_{GS} = 0V, I_S = -0.5A$	-	-	-1.3	V

Notes:

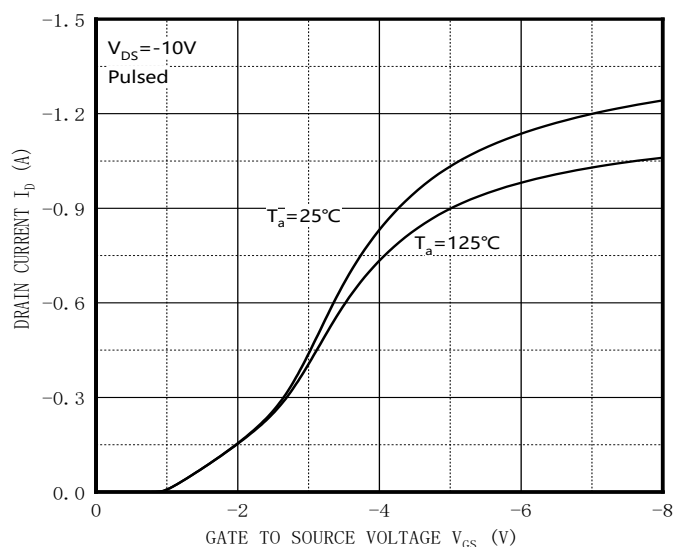
1. Repetitive rating: Pulse width limited by junction temperature.
2. Surface mounted on FR4 board, $t \leq 10s$.
3. Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
4. Guaranteed by design, not subject to production.



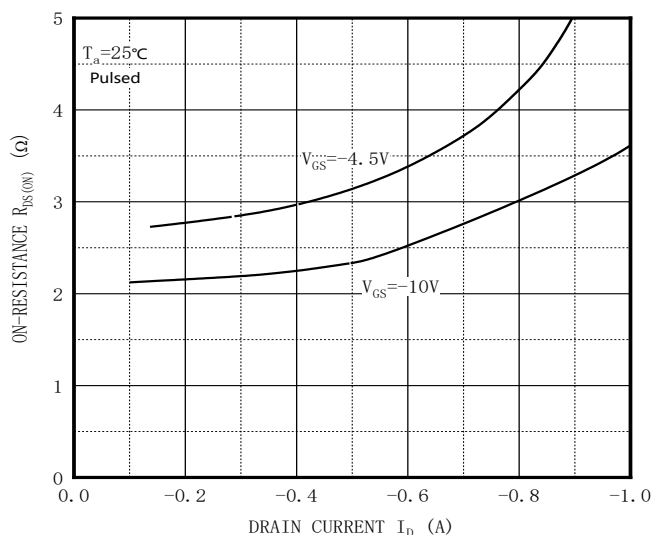
Typical Characteristics



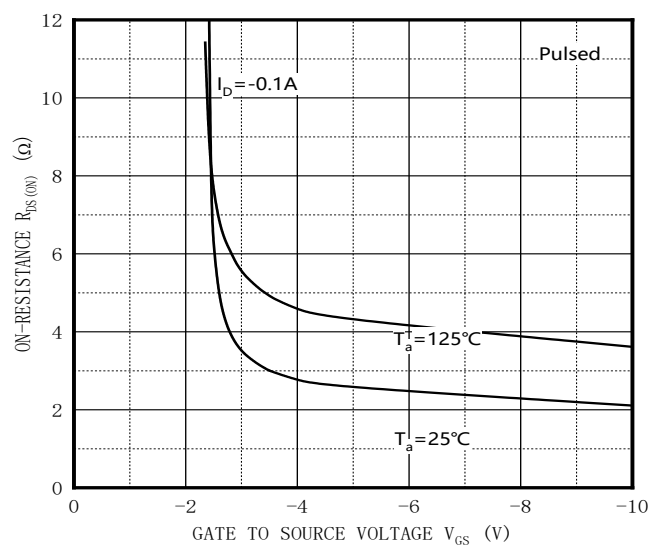
Output Characteristics



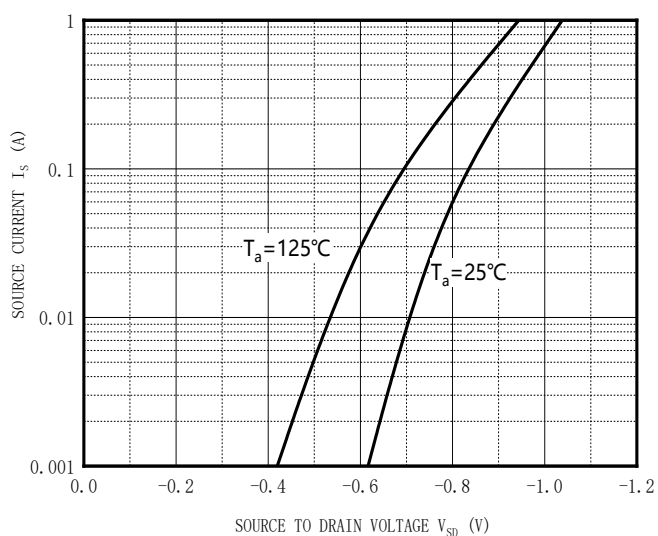
Transfer Characteristics



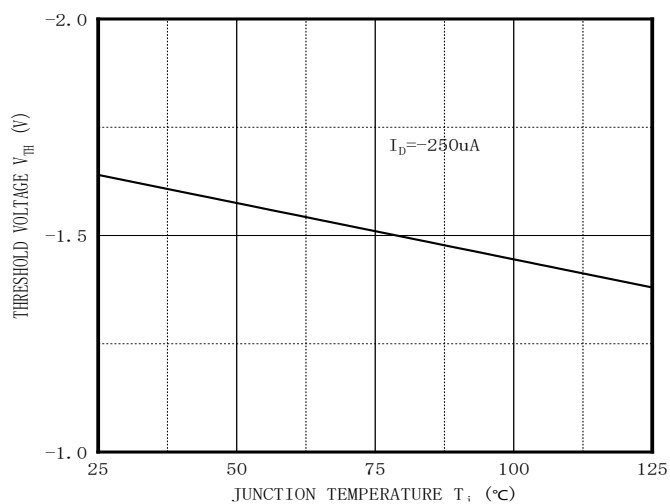
$R_{DS(on)}$ vs. I_D



$R_{DS(on)}$ vs. V_{GS}



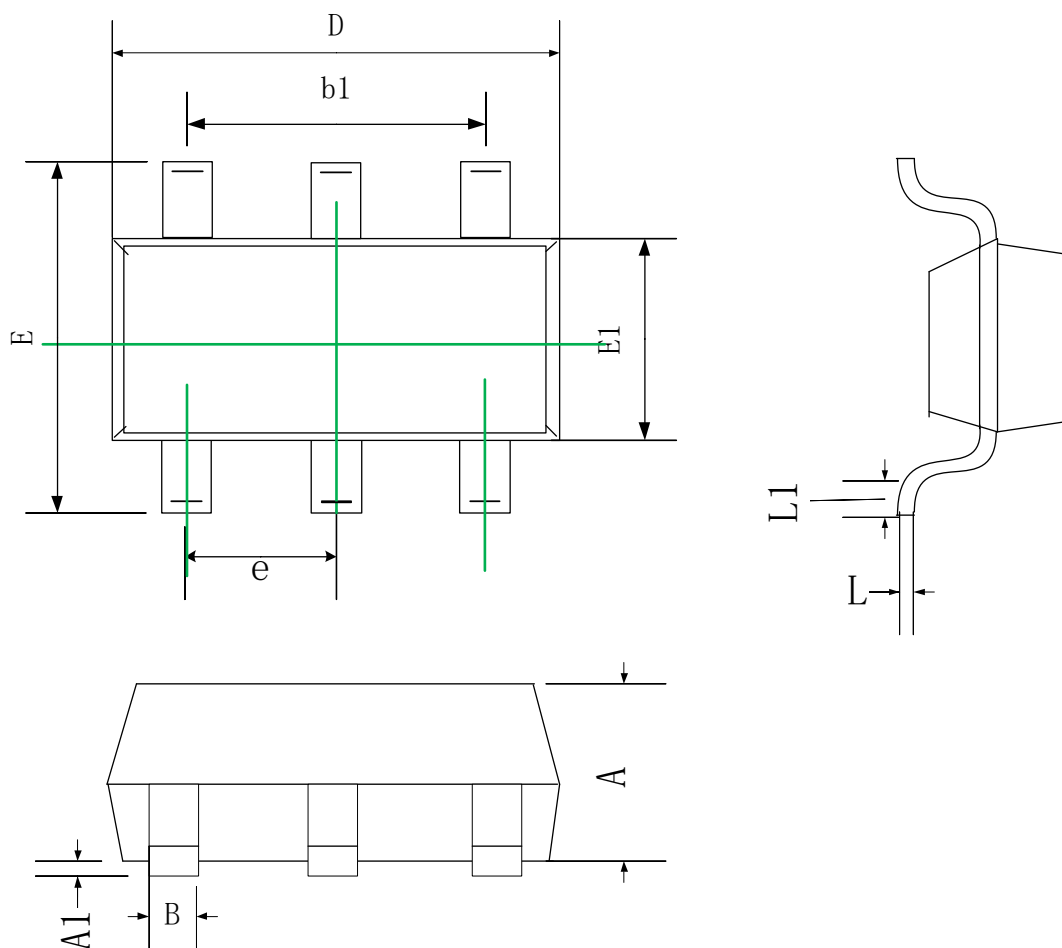
I_S vs. V_{SD}



Threshold Voltage



SOT-363 Package Information



Symbol	Dimensions In Millimeters	
	Min.	Max.
A	0.90	1.00
A1	0.00	0.10
B	0.10	0.30
b1	1.30	
D	1.80	2.20
E	2.00	2.20
E1	1.15	1.35
e	0.65 TYP.	
L	0.10	0.25
L1	0.15	0.4